

MG680 GaAs Hall Element

具有高线性度与优异温度特性的砷化镓霍尔元件

Linear GaAs Hall element with excellent thermal characteristics

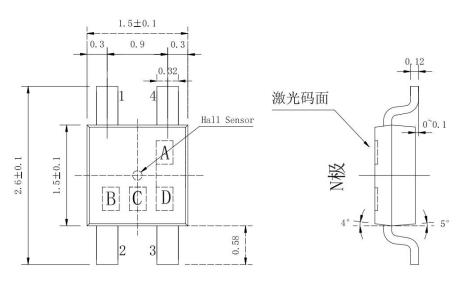
薄型 SSOT-4 封装

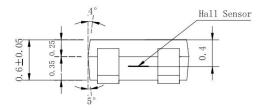
Thin-type SSOT-4 package

编带包装(每卷4,000颗)

Shipped in Packet-tape Reel (4000pcs devices per Reel)

外形尺寸图 Dimensional Drawing (Unit: mm)





引脚定义 (Pinning)		
输入 Input	1 (±)	3 (∓)
输出 Output	2 (±)	4 (∓)

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绝对最大额定值 Absolute Maximum Ratings

项目	符号	条件	范围	单位
ltem	Symbol	Conditions	Limit	Unit
最大输入电流	,	T _a = 25 °C	14	mA
Maximum Input Current	Cmax	I _a = 25 C	14	IIIA
工作温度	7		40 .125	°C
Operating Temperature Range	T opr		-40 ~ +125	
保存温度	T		40 .450	$^{\circ}$
Storage Temperature Range	T _{STG}		-40 ~ +150	

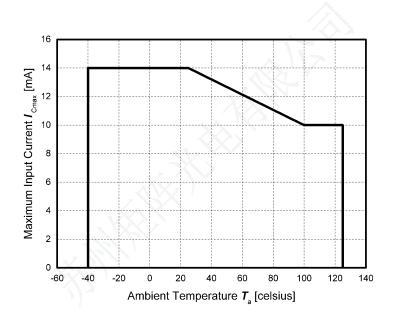


Figure 1. 最大输入电流-环境温度

Maximum input current I_{Cmax} as a function of ambient temperature T_a

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电气特性 Electrical Characteristics (RT=25℃)

项目 符号 测试环境 最小 标准 最大 标准 Symbol Item Test Condi. Min. Max. Unit Typ. 霍尔电压 $B = 50mT, I_C = 5mA$ 38 58 V_{H} m٧ Hall Voltage $T_a = RT$ 输入电阻 $B = 0mT, I_C = 0.1mA$ 750 Ω 450 R_{in} Input Resist. $T_a = RT$ $B = 0mT, I_C = 0.1mA$ 输出电阻 1000 2000 Ω **R**out Output Resist. $T_a = RT$ 非平衡电压 $B = 0mT, I_C = 5mA$ -6 +6 m۷ V_{os} Offset Voltage $T_a = RT$ 霍尔电压温度系数 $B = 50mT, I_C = 5mA,$ 0.06 %/℃ $|\alpha V_H|$ Temp. Coeffi. of V_H $T_a = 25^{\circ}C \sim 125^{\circ}C$ $B = 0mT, I_C = 0.1mA,$ 输入电阻温度系数 %/℃ αR_{in} 0.3 Temp. Coeffi. of Rin $T_a = 25^{\circ}C \sim 125^{\circ}C$ 霍尔电压线性度 B = 0.1 - 0.5T, $I_C = 5mA$ ΔK -2 +2 %

Table 1. MG680 电气特性表 Electrical Characteristics of MG680

Note:

1.
$$V_{\rm H} = V_{\rm H-M} - V_{\rm os}$$

Linearity of V_H

in which $\emph{V}_{\rm H-M}$ is the Output Hall Voltage, $\emph{V}_{\rm H}$ is the Hall Voltage and $\emph{V}_{\rm os}$ is the offset Voltage

 $T_a = RT$

under the identical electrical stimuli.

2.
$$\alpha V_{\rm H} = \frac{1}{v_{\rm H} (T_{a1})} \times \frac{v_{\rm H} (T_{a2}) - v_{\rm H} (T_{a1})}{T_{a2} - T_{a1}} \times 100$$
 $T_{a1} = 25$ °C, $T_{a2} = 125$ °C

3.
$$\alpha R_{\text{in}} = \frac{1}{R_{\text{in}} (T_{a1})} \times \frac{R_{\text{in}} (T_{a2}) - R_{\text{in}} (T_{a1})}{T_{a2} - T_{a1}} \times 100$$
 $T_{a1} = 25$ °C, $T_{a2} = 125$ °C

4.
$$\Delta K = \frac{K(B_1) - K(B_2)}{\frac{K(B_1) + K(B_2)}{2}} \times 100$$
 $K = \frac{V_H}{I_c \times B}$ $B_1 = 0.5T, B_2 = 0.1T$

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特性曲线图 Characteristic Curves

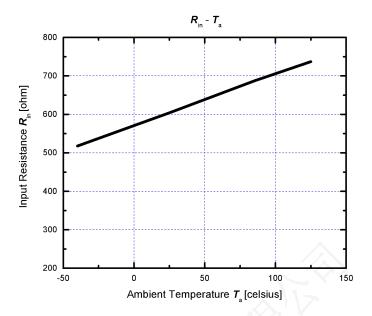


Figure 2. 输入电阻-环境温度 Input resistance $extbf{\emph{R}}_{ ext{in}}$ as a function of ambient temperature $extbf{\emph{T}}_{ ext{a}}$

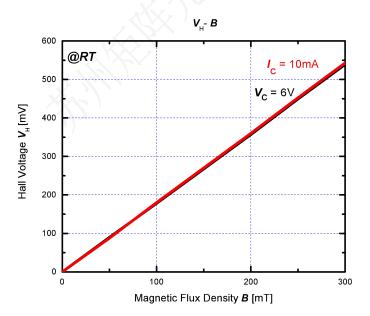


Figure 3. 霍尔电压-磁感应强度 Hall voltage \emph{V}_{H} as a function of magnetic flux density $\emph{\textbf{B}}$

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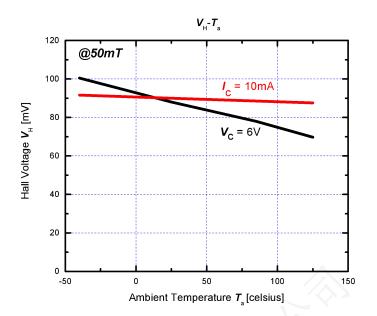


Figure 4. 霍尔电压-环境温度 Hall voltage V_H as a function of ambient temperature T_a

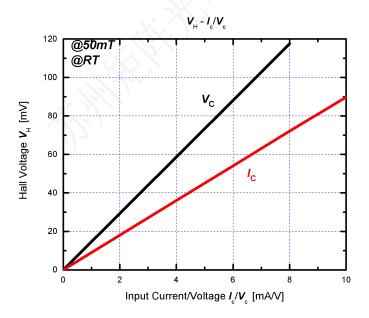


Figure 5. 霍尔电压-驱动电流/驱动电压 Hall voltage \emph{V}_{H} as a function of electrical stimuli $\emph{I}_{c}/\emph{V}_{c}$



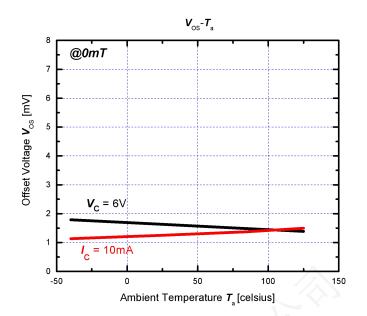


Figure 6. 非平衡电压-环境温度 Offset voltage V_{OS} as a function of ambient temperature T_a

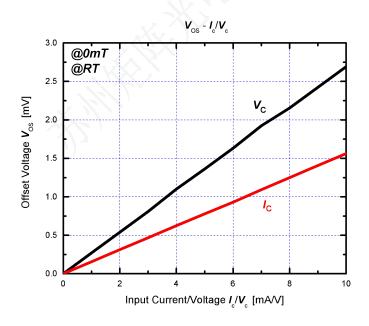


Figure 7. 非平衡电压-驱动电流/驱动电压 Offset voltage \emph{V}_{OS} as a function of electrical stimuli \emph{I}_c/\emph{V}_c



可靠性测试项目 Reliability Test Terms

Table 2. 可靠性测试项目,条件和持续时间 Reliability Test Terms, Conditions and Duration

Na	项目	測试条件	持续时间	
No.	Terms	Conditions	Duration	
1	高温存储试验 High Temperature Storage (HTS)	[JEITA EIAJ ED-4701] 7 _a =150 (0 ~ +10)°C	1000 hr	
2	热循环试验 Heat Cycle (HC)	[JEITA EIAJ ED-4701] $ {\it T}_a = -55^{\circ}\text{C} \sim 150^{\circ}\text{C} $ high temp normal temp low temp. $ 30\text{min} - 5\text{min} - 30\text{min} $	50 cycles	
3	高温高湿存储试验 Temp. Humidity Storage (THS)	【JEITA EIAJ ED-4701】 <i>T₃</i> =85±3°C, <i>RH</i> =85±5%	1000 hr	
4	回流焊试验 Reflow Soldering (RS)	【JEITA EIAJ ED-4701】 260±5°C	10 sec	
5	高温带电老化试验 High Temp. Operating (HTO)	7 _a =125°C , / _c =8mA	1000 hr	

判定基准:

- 霍尔电压 $V_{\rm H}$ 和输入/输出电阻 $R_{\rm in/out}$ 的数值变化幅度小于 $\pm 20\%$
- 非平衡电压 $V_{\rm os}$ 的数值变化幅度小于 $\pm 8 {
 m mV}$
- 在表 1 中的其他参数仍然在表 1 的规定范围内

Criteria:

- Variation of Hall Voltage $V_{\rm H}$ and input/output resistances $R_{\rm in/out}$ are less than $\pm 20\%$ of initial value.
- Variation of offset voltage V_{os} is within ±8mV.
- Other parameters in Table 1. are still within their ranges stated in Table 1.

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焊接条件

助焊剂材料

- 使用树脂基助焊剂,避免使用有机或无机酸基及水溶性助焊剂。

助焊剂的清洗条件

- 使用乙醇或异丙醇作为清洗剂。
- 工艺温度≤50℃。
- 持续时间不超过 5 分钟。

焊接方法

焊接方法	焊接方法说明	焊接温度
回流法	在高温下进行焊接的方法	最高 260℃,10 秒以内
波峰焊	在镀锡缸中完成焊接的方法	最高 260℃,10 秒以内
烙铁法	使用烙铁修正引脚焊接部分的方法	最高 350℃,3 秒以内

焊接温度范围

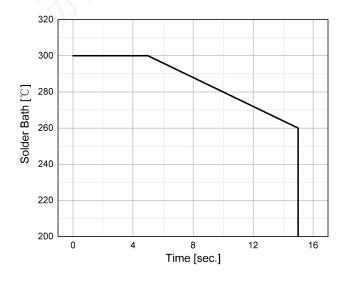


Figure 8. (参考)浸入焊接条件

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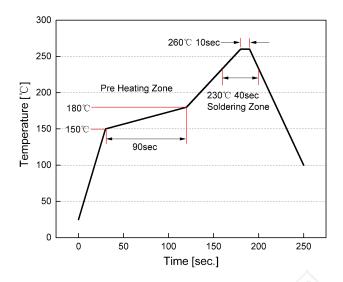


Figure 9. (参考)回流焊条件

ESD防护

本产品对 ESD (静电放电)敏感,接触带有 ESD-Caution 标记的霍尔元件时,环境要求如下:

- 环境不太可能出现静电荷(例如,相对湿度超过 40%RH)。
- 接触产品时应该穿戴防静电服和腕带。
- 对直接接触产品的设备或容器实施防静电措施。

存储防护

- 产品应储存在适当的温度和湿度环境下(5至35°C,40%至85%RH),且使产品远离氯和腐蚀性气体。
- 即使在适当的条件下,长期存放也可能导致产品的可焊接性和电气性能降低。针对长期存放的产品,应 该在使用前应检查其可焊性。
- 如果储存超过 2 年,建议储存在氮气环境中。大气中的氧气会氧化产品的引线,导致引线可焊接性变差。

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安全防护

- 请勿通过燃烧,粉碎或化学处理等方式将本产品变成气体,粉末或液体。
- 丢弃本产品时,请遵守法律和公司规定。



Soldering Conditions

The following conditions should be preserved. Solder ability should be checked by yourself, because it is depend on solder paste material and other parameters.

Material of solder flux

- Use the resin based flux and refrain from using organic or inorganic acid based and water-soluble one.

Cleansing of solder flux conditions

- Use Ethanol or Isopropyl alcohol as cleansing material.
- Process temperature should be 50°C or less.
- Duration should be 5min or less.

Hand-Soldering

 Solder the leads to PC board at the point(part from the body) at 260°C for 10 seconds or 350°C for less than 3 seconds.

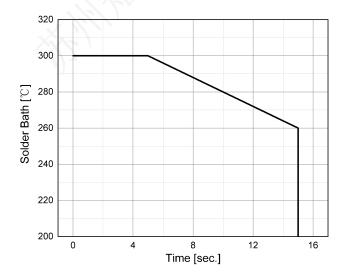


Figure 8. (Reference) Conditions of Dip Soldering

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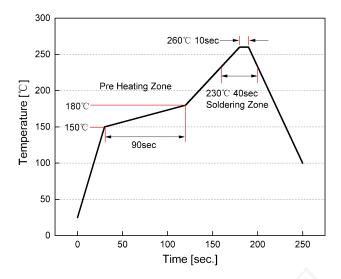


Figure 9. (Reference) Conditions of Reflow Profile

Precautions for ESD

This product is the device that is sensitive to ESD (Electrostatic Discharge). Handling Hall Elements with the ESD-Caution mark under the environment in which

- Static electrical charge is unlikely to arise. (Ex; Relative Humidity; over 40% RH).
- Wearing the antistatic suit and wristband when handling the devices.
- Implementing measures against ESD as for containers that directly touch the devices.

Precautions for Storage

- Products should be stored at an appropriate temperature and humidity (5 to 35°C, 40 to 85%RH). Keep products away from chlorine and corrosive gas.
- Long-term storage may result in poor lead solder ability and degraded electrical performance even under proper conditions. For those parts, which stored long -term shall be check solder ability before it

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is used.

 For storage longer than 2 years, it is recommended to store in nitrogen atmosphere. Oxygen of atmosphere oxidizes leads of products and lead solder ability get worse.

Precautions for Safety

- Do not alter the form of this product into a gas, powder or liquid through burning, crushing or chemical processing.
- Observe laws and company regulations when discarding this product.

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文件修改历史

版本	日期	描述
1.0	2022.10.19	初始版本发行

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